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β-decay half-lives of neutron-rich nuclides in the A = 100–110 mass region

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β-decay half-lives of neutron-rich nuclides in the A = 100–110 mass region have been measured using an implantation station installed inside of the Summing Na(Tl) (SuN) detector at the National Superconducting Cyclotron Laboratory. Accurate half-lives for these nuclides are important for nuclear astrophysics, nuclear structure, and nuclear technology. The half-lives from the present work are compared with previous measurements, showing overall good agreement.

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I. INTRODUCTION

In the field of nuclear astrophysics, the rapid neutron-capture process, or r process, is the mechanism cited to explain the abundance of roughly half of the stable nuclides beyond the iron peak that are observed in the solar system [1]. Reaction network calculations of the r process rely on accurate nuclear properties, such as β-decay half-lives and β-delayed neutron emission probabilities, of the participating nuclides in order to calculate the final abundance pattern, which is then compared with observations from the solar system and metal-poor halo stars [2]. Accurate half-lives for these nuclides are important for nuclear astrophysics, nuclear structure, and nuclear technology. The half-lives from the present work are compared with previous measurements, showing overall good agreement.

Recently, a kilonova has been observed by various observatories [3] in coincidence with the detection of gravitational waves from the merger of two neutron stars [4]. A kilonova is the electromagnetic counterpart to gravitational waves from certain mergers of compact objects, and is powered by the radioactive decay of the newly created r-process nuclides [5]. The nuclear properties of the decaying nuclides will have a direct impact on the observed electromagnetic emission from a kilonova [6].

In the field of nuclear structure, β decay is a tool to study the shapes of certain nuclides. By comparing theoretical and experimental Gamow-Teller transition strength, B(GT), distributions, the shape of the ground state of a nuclide can be identified as oblate, spherical, or prolate [7] in particular cases. Since the experimental B(GT) depends inversely on the half-life of the nuclide, an accurate half-life is necessary for a proper comparison to the theoretical B(GT). This is especially true for many neutron-rich nuclides in the A = 100–110 mass region, for which the B(GT) is predicted to be sensitive to the deformation [8,9].

In the field of nuclear technology, calculating the decay heat of fission products is important for the operation of a nuclear reactor [10]. These summation calculations rely on a large amount of nuclear data of the fission products in a reactor, one being the half-life. A report by the Nuclear Energy Agency [11] has requested a reevaluation of nuclear data for certain nuclides in order to more accurately calculate the decay heat. Many of these neutron-rich nuclides are around the A = 100–110 mass range [12].

In this paper, we provide half-life measurements for neutron-rich nuclides in the A = 100–110 mass region. Half-lives for many nuclides in this paper were measured decades ago in experiments that performed chemical separation of fission fragments. Both the separation and identification of fragments in these past experiments were challenging, and authors often reported possible contamination issues. For this reason, the present work provides new measurements of half-lives in the A = 100–110 mass region using a consistent technique. The experimental details are presented in Sec. II, the analysis procedure is described in Sec. III, the half-life measurements are reported in Sec. IV, and conclusions are given in Sec. V.

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II. EXPERIMENTAL DETAILS

The experiment was performed at the National Superconducting Cyclotron Laboratory (NSCL) at Michigan State University. The Coupled Cyclotron Facility produced a primary beam of $^{124}$Sn$^{4+}$ with an energy of 120 MeV/u, which impinged upon a $^9$Be production target with a thickness of 403 mg/cm$^2$. The resulting ions from the fragmentation reaction were filtered with the A1900 fragment separator [13], using a 60 mg/cm$^2$ aluminum wedge, to produce a secondary cocktail beam that consisted of neutron-rich nuclides with atomic numbers ranging from 39 to 43 and mass numbers ranging from 100 to 110. Due to the use of the full momentum acceptance (5%) of the separator, a thin, plastic (BC-400), position-sensitive scintillator at the intermediate dispersive image was used to provide information about the momentum (and time of flight) of an ion. After the A1900 fragment separator, the ions were delivered to the experimental end station, which, ordered along the beam line, consisted of two silicon PIN detectors, an implantation station, and the Summing NaI(Tl) (SuN) detector. The implantation station consisted of a double-sided silicon-strip detector (DSSD) and a silicon surface barrier detector. Signals from all of the detectors in the end station were recorded with the NSCL Digital Data Acquisition System (DDAS) [14].

The two silicon PIN detectors were installed upstream from SuN and provided information about the energy loss and time of flight of an ion. The first and second PIN detectors, which had thicknesses of 488 and 503 $\mu$m, respectively, were rotated 40° to create effective thicknesses of approximately 637 and 657 $\mu$m, respectively. The angle of rotation was chosen so that, after energy deposition in the PIN detectors, the ions of interest would stop, or implant, at the center of the DSSD.

After the PIN detectors, there was a collimator (3.8 cm diameter) to collect ions that would have otherwise been deposited on the inside of the beam pipe and not arrive at the downstream implantation station. A wall of lead bricks was built between the collimator and SuN to prevent random coincidences between $\gamma$ rays from accumulated activity on the collimator and $\gamma$ rays from $\beta$ decays in the implantation station.

The implantation station was installed in the center of the borehole of SuN. The DSSD was positioned at the geometric center of SuN, and was used to detect high-energy ion implantations and subsequent low-energy $\beta$-decay electrons, which were spatially and temporally correlated to one another [15]. The correlation procedure is described in Sec. III A. Simultaneous detection of implantations (depositing energy on the order of GeV in the DSSD) and $\beta$-decay electrons (depositing energy on the order of keV and MeV in the DSSD) was achieved with dual-gain preamplifiers. The low-gain stage was used for detecting implantations, while the high-gain stage was used for detecting $\beta$-decay electrons. Manufactured by Micron Semiconductor Ltd. [16], the DSSD was designed to fit inside the borehole of SuN using the BB8 design. The silicon chip of the DSSD had a thickness of 1030 $\mu$m, dimensions of 21.8 mm by 21.8 mm, and an active area of 20.0 mm by 20.0 mm. There were 16 horizontal strips on the front side and 16 vertical strips on the back side, effectively creating 256 pixels. All strips had a pitch of 1250 $\mu$m. Roughly 25 mm downstream from the DSSD was a silicon surface barrier detector that acted as a veto detector to detect any ions (particularly light, charged particles) that did not stop in the DSSD. The veto detector was manufactured by ORTEC with model number BU-014-300-500 (active area of 300 mm$^2$ and depletion depth of 300 $\mu$m).

An external trigger, which was a “front-back coincidence” and configured in hardware, was required to record signals in the DSSD. For a given side of the DSSD, an OR signal was generated whenever a strip produced a signal above threshold. Whenever an OR from the front side and an OR from the back side overlapped in time, an AND signal was created and used as a validation window for recording the raw signals that originally produced the OR signals. The external trigger reduced the recording of random noise, which enabled the lowering of trigger thresholds and therefore increased the detection efficiency of low-energy $\beta$-decay electrons.

Surrounding the implantation station was the SuN detector [17] to employ the total absorption spectroscopy (TAS) technique [18]. SuN is a right-circular cylinder divided into eight segments of NaI(Tl), with each segment containing three photomultiplier tubes. The segmentation of SuN is powerful in that both the total energy deposited in SuN as well as the energy deposited in each segment is recorded for a given event. For $\beta$-decay experiments with SuN [19,20], this translates to knowing the level populated in the daughter nucleus and also the possible subsequent electromagnetic deexcitation of that level in the form of $\gamma$ rays. Adding the histograms from all eight segments together produces the sum-of-segments spectrum in which individual $\gamma$ rays can be identified, while adding together the energies of all eight segments on an event-by-event basis produces the TAS spectrum in which sum peaks that correspond to levels can be identified.

This experiment was the first-ever application of the TAS technique with a fast beam produced via projectile fragmentation. Results from later experiments with roughly the same experimental setup have already been published [20–22]. The extracted $\beta$-decay feeding intensity distributions for the nuclides in the present work will be presented in forthcoming papers. Here, we used the TAS and sum-of-segments spectra to apply stringent conditions for identifying the nuclides of interest and extracting their half-lives.

III. ANALYSIS

A. Correlations

In software, events were created using a 2 $\mu$s coincidence time window and classified as either an implantation or decay. Events were classified as an implantation if there was a signal in both of the silicon PIN detectors, there was a measurement of the time of flight and momentum of an ion, there was at least one strip that fired on both sides of the DSSD in the low-gain stage, and there was no signal in the veto detector. The strips of the DSSD in the low-gain stage were gain matched with secondary beam. The pixel in which the
Implantation occurred was defined by the strip that received the maximum energy deposition on each side. The secondary beam was defocused to try to illuminate as much of the surface of the DSSD as possible, which resulted in an average time between consecutive implantations for a given pixel near the center of the DSSD of approximately 12 seconds.

Events were classified as a decay if neither silicon PIN detector had a signal, there were no signals in the low-gain stage of the DSSD, there was at least one strip that fired on both sides of the DSSD in the high-gain stage, and there was no signal in the veto detector. The pixel in which the decay occurred was defined in the same way as described for an implantation. The strips of the DSSD in the high-gain stage were calibrated with sources of \(^{228}\text{Th}\), \(^{241}\text{Am}\), and \(^{249}\text{Cf}\). The thresholds for the strips in the high-gain stage ranged from 150 to 200 keV.

Decays were correlated to an implantation according to the following logic. First, when a decay was identified, implantations that previously occurred were searched for in the correlation field, and whichever implantation was closest in time to the decay was selected as a candidate to be correlated to the decay. In the present work, a single-pixel correlation field was used, meaning the implantation and decay had to have occurred in the same pixel. Second, there had to have been a sufficient amount of time that passed between the candidate implantation and the previous implantation in the same pixel. This condition helps to remove ambiguity of the decay originating from the most recent implantation in the correlation field. Third, the decay had to have happened within a certain amount of time of the implantation known as the correlation time window. Within this correlation procedure, not all decay events will be correlated to the correct implantation event, resulting in random correlations. These random correlations were characterized by performing correlations backward in time [23].

### TABLE I. Half-lives from the present work along with previous measurements.

<table>
<thead>
<tr>
<th>Nuclide</th>
<th>Level(s) (keV)</th>
<th>(\gamma) ray(s) (keV)</th>
<th>Present work (s)</th>
<th>Previous measurements (s)</th>
</tr>
</thead>
<tbody>
<tr>
<td>(^{99}\text{Y})</td>
<td>724.5</td>
<td>602.7</td>
<td>1.27(25)</td>
<td>1.36(11) [26], 1.40(7) [26], 1.486(7) [27], 1.47(2) [28], 1.51(8) [29], 1.45(22) [30], 1.48(2) [31], 1.1(3) [32,33]</td>
</tr>
<tr>
<td>(^{101}\text{Zr})</td>
<td>1840–2040</td>
<td>1740–2040</td>
<td>2.27(12)</td>
<td>2.0(3) [34,35], 2.2(3) [34,35], 2.5(1) [36], 3.3(6) [37], 2.4 [38]</td>
</tr>
<tr>
<td>(^{102}\text{Zr})</td>
<td>599.48</td>
<td>535.13, 599.48</td>
<td>2.01(8)</td>
<td>2.9(2) [39], 2.1 [38]</td>
</tr>
<tr>
<td>(^{102m}\text{Nb})</td>
<td>296.61</td>
<td>296.61</td>
<td>1.33(27)</td>
<td>1.3(2) [39]</td>
</tr>
<tr>
<td>(^{103}\text{Nb})</td>
<td>102.6</td>
<td>102.6</td>
<td>1.34(7)</td>
<td>1.5(2) [39], 1.5(2) [40], 1.3(1) [41,42]</td>
</tr>
<tr>
<td>(^{104m}\text{Nb})</td>
<td>4640–7240</td>
<td>192.2</td>
<td>0.97(10)</td>
<td>0.8(2) [39], 0.9(2) [43,44], 0.99(7) [45], 1.0(1) [31]</td>
</tr>
<tr>
<td>(^{109}\text{Tc})</td>
<td>1158.7, 1267.8</td>
<td>1158.7, 1267.8</td>
<td>0.87(7)</td>
<td>1.14(3) [46], 1.04(11) [46], 0.82(10) [31], 0.86(3) [47], 0.93(3) [48,49], 0.9(1) [49,50], 1.4(4) [51]</td>
</tr>
</tbody>
</table>

A decay curve was created for each nuclide of interest by histogramming the time difference between the implantation of an ion and its subsequent \(\beta\) decay, and was used to extract the half-life. Isolating events in the decay curve from the nuclide of interest was obtained by simultaneously gating on a sum peak in the TAS spectrum and a \(\gamma\) ray in the sum-of-segments spectrum. This technique is detailed for a specific nuclide in Sec. IV.B.

In addition to any random correlations, in this technique there possibly are additional sources of background that must be considered. If the nuclide of interest to be isolated is the parent, these potential background sources include events from the decay of future descendants (for example, the daughter) and also from possible charge-state contaminants. Consulting the decay schemes of the parent, future descendants, and charge-state contaminant enabled the selection of events that included an established level and \(\gamma\) ray from the decay of the nuclide of interest. In addition, sum peaks and \(\gamma\) rays of higher energies were favored in order to reduce the possibility of including events from incomplete summation in the TAS spectrum and events from Compton-scattered \(\gamma\) rays in the sum-of-segments spectrum.

If applicable to certain nuclides, the ground-state-to-ground-state \(Q\) values for \(\beta\) decay [24] were used to identify appropriate gating regions in the TAS spectrum. For example, the ground-state-to-ground-state \(Q\) value for the parent \(^{104}\text{Nb}\) is 8531 keV, the daughter \(^{104}\text{Mo}\) is 2153 keV, and the charge-state contaminant \(^{101}\text{Nb}^{0+}\) is 4628 keV [24]. Therefore, counts in the TAS spectrum above approximately 4628 keV should only originate from the decay of \(^{104}\text{Nb}\).

Two decay curves were created for each gating combination, with the only difference being that one was created using forward-time correlations and the other using backward-time correlations. The distribution of backward-time correlations,
representing random correlations between implantations and decays, was fit with an exponential function, the results of which were used and held fixed as a background component while fitting the forward-time correlations with an appropriate form of the Bateman equations [25].

IV. RESULTS

In this section, we discuss each β decay separately. In Figs. 1, 3, 4, 5, 6, 7, and 8, “Data” refers to forward-time correlations, “Random Correlations Data” refers to backward-time correlations, “Random Correlations Fit” refers to the exponential fit of backward-time correlations, and “Total Fit” refers to the fit of forward-time correlations with the Bateman equations and an exponential background with fixed parameters from the fit of backward-time correlations. Table I contains a description of the selection of events in the decay curve and a comparison of the half-life from the present work with previous measurements.

A. \(^{99}\)Y\(_{60} \rightarrow ^{99}\)Zr\(_{59}\)

The half-life of \(^{99}\)Y has been previously measured in fission-based experiments [28–32], experiments using the isotope separator on-line (ISOL) technique [27], and fragmentation-based experiments [26]. The decay curve from the present work is shown in Fig. 1, and it resulted in a half-life of \(1.27 \pm 0.25\) s, in good agreement with previous measurements.

B. \(^{101}\)Zr\(_{61} \rightarrow ^{101}\)Nb\(_{60}\)

The half-life of \(^{101}\)Zr has been previously measured in fission-based experiments [34,36–38]. References [36,38] both reported a large β-decay feeding intensity to levels in \(^{101}\)Nb around 2 MeV. These measurements have been compiled in the decay scheme from ENSDF [35], which shows a group of nearby levels around 2 MeV (specifically, those levels between 1878.1 and 2030.65 keV, inclusive) that collectively have a relatively large β-decay feeding intensity. In the present work, the TAS spectrum contains a prominent sum peak around 2 MeV [see Fig. 2(a)]. Examining the sum-of-segments spectrum while gating on this sum peak shows the high-energy γ rays (between roughly 1.8 MeV and 2 MeV within the energy resolution of SuN) that have a large probability of being emitted during the deexcitation of these levels that form the sum peak [see Fig. 2(b)]. Gating on the sum peak from these levels in the TAS spectrum and γ rays in the sum-of-segments spectrum produced the decay curve shown in Fig. 3 and resulted in a half-life of \(2.27 \pm 0.12\) s, in good agreement with previous measurements.

C. \(^{102}\)Zr\(_{62} \rightarrow ^{102}\)Nb\(_{61}\)

The half-life of \(^{102}\)Zr has been previously measured in fission-based experiments [38,39]. One of those experiments

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{figure1.png}
\caption{Decay curve for \(^{99}\)Y. The selection of events in this decay curve is described in Table I. The inset shows the decay curve on a logarithmic scale.}
\end{figure}

\begin{figure}[h]
\centering
\includegraphics[width=\textwidth]{figure2.png}
\caption{β-delayed γ-ray spectra for decay events correlated to \(^{101}\)Zr implantations with a correlation time window of one second. The backward-time correlations (random background) have been subtracted from the forward-time correlations. The top panel, labeled (a), shows the TAS spectrum, and the red, cross hatches indicate the selection of events used to examine the individual γ rays in the sum-of-segments spectrum in the bottom panel. The bottom panel, labeled (b), shows the sum-of-segments spectrum only for certain events in the TAS spectrum as indicated in the top panel. Individual γ rays identified within the energy resolution of SuN are labeled. In (b), the red cross hatches indicate the selection of events used to create the decay curve for \(^{101}\)Zr, which is shown in Fig. 3.}
\end{figure}
only indirectly measured the half-life of $^{102}$Zr by following the growth and decay of the daughter $^{102}$Nb [39]. A decay curve from the present work is shown in Fig. 4 and the half-life from the present work is $2.01 \pm 0.08$ s, in good agreement with one of the two previous measurements.

D. $^{102m}$Nb$_{61}$ $\rightarrow$ $^{102}$Mo$_{60}$

The half-life of $^{102m}$Nb has been previously measured in fission-based experiments [39]. For the decay of $^{102}$Zr in the present work, there is an intense sum peak in the TAS spectrum at approximately 296 keV and a very intense peak with the same energy in the sum-of-segments spectrum. However, the decay schemes for the parent $^{102}$Zr [52] and the charge-state contaminant $^{99}$Zr$^{39+}$ [33] do not list, around this energy, any levels that could be populated or $\gamma$ rays that could be emitted during their respective $\beta$ decays. Meanwhile, a decay scheme exists for the ground state but not the $\beta$-decaying isomeric state of the daughter $^{102}$Nb [52]. No evidence was found in the TAS spectrum for the decay of the ground state of the daughter, which agrees with Ref. [53] in terms of the $\beta$ decay of $^{102}$Zr populating levels in $^{102}$Nb that are built on top of the $\beta$-decaying isomeric state. The origin of the peaks at approximately 296 keV in the TAS and sum-of-segments spectra was assigned to be from the $\beta$-decaying isomeric state populating the first excited state in $^{102}$Mo at 296.61 keV. Gating on both this sum peak in the TAS spectrum and $\gamma$ ray in the sum-of-segments spectrum produced the decay curve in Fig. 5 and resulted in a half-life of $1.33 \pm 0.27$ s, in good agreement with the previous measurement. In fitting the decay curve with the Bateman equations that described the growth and decay of $^{102m}$Nb, the half-life of $^{102}$Zr as determined in Sec. IV C was held constant.

E. $^{103}$Nb$_{62}$ $\rightarrow$ $^{103}$Mo$_{61}$

The half-life of $^{103}$Nb has been previously measured in fission-based experiments [39–41]. The decay curve from
A fit of the decay curve gated on only this the longer-lived ground state and shorter-lived isomeric state. Reference [44] identified the 192.2 keV γ-ray as originating from predominately the longer-lived ground state. In the present work, this γ-ray has no significant peak in the sum-of-segments spectrum. With little evidence found for the longer-lived ground state in the decay curves and sum-of-segments spectrum, the conclusion was made that the fragmentation reaction in the experiment of the present work populated primarily the shorter-lived isomeric state, unlike all the previous experiments that produced both states of $^{104}$Nb through fission. A decay curve from the present work is shown in Fig. 7 and the half-life from the present work is 0.97 ± 0.10 s, in good agreement with previous measurements.

The half-life of $^{104}$Nb has been previously measured in fission-based experiments [31, 47, 48, 50, 51] and fragmentation-based experiments [46]. The decay curve from the present work is shown in Fig. 8 and resulted in a half-life of 0.87 ± 0.07 s, in good agreement with previous measurements.

The half-life of $^{109}$Tc has been previously measured in fission-based experiments [31, 47, 48, 50, 51] and fragmentation-based experiments [46]. The decay curve from the present work is shown in Fig. 7 and the half-life from the present work is 0.97 ± 0.10 s, in good agreement with previous measurements.

V. CONCLUSIONS

Using the capabilities of an implantation station inside of a segmented total absorption spectrometer, the β-decay half-lives of neutron-rich nuclides in the A = 100–110 mass region were measured. Accurate half-lives in this mass region are important for nuclear astrophysics, nuclear structure, and nuclear technology. Many of these nuclides had their half-lives measured decades ago and were produced by the separation of fission products, which may cause uncertainty to surround the origin of γ-rays that were gated on to produce decay curves. There is overall good agreement between the half-lives in the present work and the previous measurements, and the present work is in better agreement with one of the two disparate half-life values for $^{102}$Zr.

There are multiple ways to improve the technique so that the half-life uncertainties are reduced in future experiments. One way to improve the technique is to reduce the background from random correlations. This could be achieved by lowering the beam rate during the experiment in order to increase the amount of time between consecutive implantations for a given pixel in the DSSD. Unfortunately, this approach would also reduce the statistics in the decay curves. Another way to improve the technique is in the future to measure the total kinetic energy of each ion implanted in the DSSD so that charge-state separation may be performed. With the potential background from possible charge-state contaminants removed, deciding where to simultaneously gate on the TAS spectrum and sum-of-segments spectrum would likely be more straightforward.

Regarding the nuclides studied in the present work, many questions concerning nuclear structure and nuclear astrophysics can be found in Refs. [8, 9]. One question from these
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[16] Micron Semiconductor Ltd., available online at http://www.micronsemiconductor.co.uk/


